

L6234

Three phase motor driver

Features

- Supply voltage from 7 to 52 V
- 5 A peak current
- R_{DSon} 0.3 Ω typ. value at 25 °C
- Cross conduction protection
- TTL compatible driver
- Operating frequency up to 150 kHz
- Thermal shutdown
- Intrinsic fast free wheeling diodes
- Input and enable function for each half bridge
- 10 V external reference available

Description

The L6234 is a triple half bridge to drive a brushless DC motor.

It is realized in BCDmultipower technology which combines isolated DMOS power transistors with CMOS and Bipolar circuits on the same chip.

By using mixed technology it has been possible to optimize the logic circuitry and the power stage to achieve the best possible performance.

Table 1. Device summary



The output DMOS transistors can sustain a very high current due to the fact that the DMOS structure is not affected by the second breakdown effect, the RMS maximum current is practically limited by the dissipation capability of the package.

All the logic inputs are TTL, CMOS and μ P compatible. Each channel is controlled by two separate logic input.

L6234 is available in 20 pin PowerDIP package (16+2+2) and in PowerSO20.

Order code	Package	Packing
L6234	PowerDIP20	Tube
L6234PD	PowerSO20	Tube
L6234PD013TR	PowerSO20	Tape and reel

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1 Block diagram







2 Pin connections





Table 2. Pin functions

PowerDIP	PowerSO20	Name	Function
1	6	OUT 1	
20	5	OUT 2	Output of the channels 1/2/3.
10	15	OUT 3	
2	7	IN 1	Logic input of channels 1/2/3. A logic HIGH level (when the
19	4	IN 2	corresponding EN pin is HIGH) switches ON the upper DMOS
9	14	IN 3	corresponding low side DMOS Power.
3	8	EN 1	
18	3	EN 2	Enable of the channels 1/2/3. A logic LOW level on this pin switches off both power DMOS of the related channel
8	13	EN 3	Switches on both power Divido of the related channel.
4,7	9, 12	Vs	Power supply voltage.
14	19	SENSE2	A sense resistor connected to this pin provides feedback for motor current control for the bridge 3.
17	2	SENSE1	A sense resistor connected to this pin provides feedback for motor current control for the bridges 1 and 2.
11	16	VREF	Internal voltage reference. A capacitor connected from this pin to GND increases the stability of the Power DMOS drive circuit.
12	17	VCP	Bootstrap oscillator. Oscillator output for the external charge pump.
13	18	VBOOT	Overvoltage input to drive the upper DMOS
5,6 15,16	1,10 11,20	GND	Common ground terminal. In PowerDIP and SO packages these pins are used to dissipate the heat forward the PCB.



3 Thermal data

Table 3.	Thermal	data

Symbol	Parameter	DIP16+2+2	PowerSO20	Unit
R _{th j-pin}	Thermal resistance, junction to pin	12 ⁽¹⁾	_	°C/W
R _{th j-amb1}	Thermal resistance, junction to ambient	40 (2)	_	°C/W
R _{th j-amb2}	Thermal resistance, junction characteristics) to ambient	50 ⁽³⁾	-	°C/W
R _{th j-case}	Thermal resistance junction-case	-	1.5	°C/W

1. The thermal resistance is referred to the thermal path from the dissipating region on the top surface of the silicon chip, to the points along the four central pins of the package, at a distance of 1.5 mm away from the stand-offs.

- If a dissipating surface, thick at least 35 mm, and with a surface similar or bigger than the one shown in *Figure 3*, is created making use of the printed circuit. Such heatsinking surface is considered on the bottom side of an horizontal PCB (worst case).
- 3. If the power dissipating pins (the four central ones), as well as the others, have a minimum thermal connection with the external world (very thin strips only) so that the dissipation takes place through still air and through the PCB itself. It is the same situation of note 2, without any heatsinking surface created on purpose on the board.







4 Maximum ratings

Table 4.	Absolute	maximum	ratings
Table 4.	ADSUIULE	maximum	raunys

Symbol	Parameter	Value	Unit
V _S	Power supply voltage	52	V
V_{IN}, V_{EN}	Input enable voltage	- 0.3 to 7	V
I _{peak}	Pulsed output current ⁽¹⁾	5	А
V _{SENSE}	Sensing voltage (DC voltage)	-1 to 4	V
V _{boot}	Bootstrap peak voltage	62	V
V _{OD}	Differential output voltage (between any of the 3 OUT pins)	60	V
f _C	Commutation frequency	150	kHz
V_{REF}	Reference voltage	12	V
P _{tot}	Total power dissipation L6234PD, $T_A = 70^{\circ}C$	2.3	W
P _{tot}	Total power dissipation L6234, $T_A = 70^{\circ}C$	1.6 ⁽²⁾	W
T _{stg} , T _j	Storage and junction temperature range	-40 to 150	°C

1. Pulse width limited only by junction temperature and the transient thermal impedance

2. Mounted on board with minimized copper area

4.1 Recommended operating conditions

Table 5.	Recommended operating conditions

Symbol	Parameter	Value	Unit
V _S	Supply voltage	7 to 42	V
V _{OD}	Peak to peak differential voltage (between any of the 3 out pins)	52	V
1	DC output current powerSO20 ($T_A = 25^{\circ}C$)	4	А
lout	DC output current powerDIP ($T_A = 25^{\circ}C$) with infinite heatsink	2.8	А
V	Sensing voltage (pulsed t _w < 300 nsec)	-4 to 4	V
VSENSE	Sensing voltage (DC)	-1 to 1	V
Tj	Junction temperature range	-40 to 125	°C



5 Electrical characteristics

 V_S = 42 V; T_j = 25 °C unless otherwise specified.

Symbol	Parameter	Test condition	Min.	Тур.	Max.	Unit
Vs	Supply voltage		7		52	V
V _{ref}	Reference voltage			10		V
۱ _S	Quiescent supply current			6.5		mA
Τ _S	Thermal shutdown		150			°C
Τ _D	Dead time protection			300		ns
Output dm	os transistor	·				
I _{DSS}	Leakage current				1	mA
R _{DSon}	ON resistance			0.3		Ω
Source dra	in diode					
V _{SD}	Forward ON voltage	I _{SD} = 4A; EN = LOW		1.2		V
T _{RR}	Reverse recovery time	I _F = 4A		900		ns
T _{pr}	Forward recovery time			200		ns
Logic level	S					
$V_{\rm INL}, V_{\rm ENL}$	Input LOW voltage		-0.3		0.8	V
$V_{\rm INH}, V_{\rm ENH}$	Input HIGH voltage		2		7	V
I _{INL} , I _{ENL}	Input LOW current	$V_{IN}, V_{EN} = L$			-10	μA
I _{INH} , I _{ENH}	Input HIGH current	$V_{IN}, V_{EN} = H$		30		μA

 Table 6.
 Electrical characteristics



6 Circuit description

L6234 is a triple half bridge designed to drive brushless DC motors. Each half bridge has 2 power DMOS transistors with R_{DSon} = 0.3 Ω .

The 3 half bridges can be controlled independently by means of the 3 inputs IN1, IN2, IN3 and the 3 inputs EN1, EN2, and EN3. An external connection to the 3 common low side DMOS sources is provided to connect a sensing resistor for constant current chopping application.

The driving stage and the logic stage are designed to work from 7 V to 52 V.



L6234

7 Typical characteristics











Figure 8. Typical diode forward ON characteristics



Figure 10. Reference voltage vs. junction temperature





Figure 9. Reference voltage vs. supply voltage



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Figure 12. PowerSO-20 thermal resistance (mounted on Aluminium substrate)











8 Mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK[®] is an ST trademark.

Dim		mm	
Dim.	Min.	Тур.	Max.
A			3.6
a1	0.1		0.3
a2			3.3
а3	0		0.1
b	0.4		0.53
с	0.23		0.32
D (1)	15.8		16
D1	9.4		9.8
E	13.9		14.5
e		1.27	
e3		11.43	
E1 (1)	10.9		11.1
E2			2.9
E3	5.8		6.2
G	0		0.1
Н	15.5		15.9
h			1.1
L	0.8		1.1
Ν	8° (typ.)		
S	8° (max.)		
Т		10	

 Table 7.
 PowerSO20 mechanical data





Figure 16. PowerSO20 mechanical drawing



Dim.		mm	
	Min.	Тур.	Max.
a1	0.51		
В	0.85		1.40
b		0.50	
b1	0.38		0.50
D			24.80
E		8.80	
e		2.54	
e3		22.86	
F			7.10
I			5.10
L		3.30	
Z			1.27

 Table 8.
 PowerDIP20 mechanical data

Figure 17. PowerDIP20 mechanical drawing





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9 Revision history

Table 9.Document revision history

Date	Revision	Changes
01-Aug-2003	9	
15-Nov-2011	10	Updated Features in coverpage and Table 4



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